HAMAMATSU

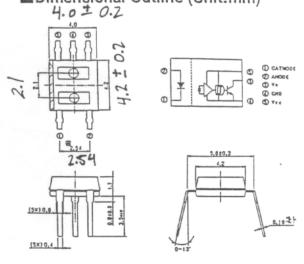
TECHNICAL DATA

PHOTOREFLECTOR (PHOTO IC OUTPUT) P5587

MABSOLUTE MAXIMUM RATINGS(Ta=25°C)

Parameter		Symbol	Value	Unit	
Input	Forward Current	IF	50	mA	
	Reverse Voltage	VR	5	V	
	Power Dissipation	P	75	mW	
Output	Supply Voltage	Vcc	-0.5 to 7	٧	
	Output Voltage	Vo	-0.5 to 7	٧	
	Output Current	lo	16	mA	
	Power Dissipation	Po	80	mW	
Operating Temperature		Topr	-25 to +85	°C	
Storage Temperature		Tstg	-30 to +85	°C	

■Dimensional Outline (Unit:mm)

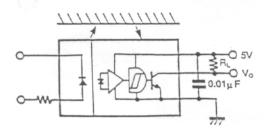


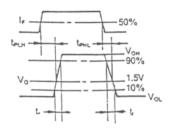
■ELECTRICAL & OPTICAL CHARACTERISTICS(Ta=25°C)

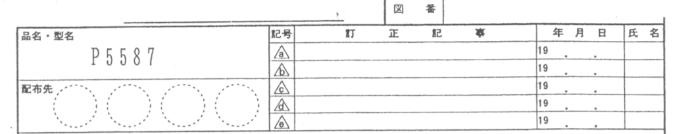
	Parameter	Symbol	Condition	Min.	Тур.	Mex.	Unit
Input	Forward Voltage	VF	I=20mA	-	1.23	1.45	V
	Reverse Current	l _R	V _R =5V	-	-	10	μА
	Terminal Capacitance	Ct	V=0V,f=1MHz	-	30	-	pF
Output	Operating Supply Voltage	Vcc		2.2	-	7	V
	Low Level Output Voltage	Vol	Vcc=5V,lot=4mA,lr=0mA	-	0.1	0.4	V
	High Level Output Current	Іон	Vcc=Vo=5V,l _F =15mA	-	-	10	μA
	Low Level Supply Current	lccL	Vcc=5V,I _F =0mA		1.3	3.0	mA
	High Level Supply Current	Іссн	Vcc=5V,I _F =15mA	-	1.3	3.0	mA
	L→H Threshold Input Current	lfu	Vcc=5V,R _L =1.2kΩ,d=3mm Reflected Surface: White Paper (Reflectivity 90% Min.)		4.0	10	mA
Transfer	Hysteresis		IFHL / IFLH		0.8	-	-
Characteristics	L→H Propagation Delay Time①	tpun		-	-	20	μs
	H→L Propagation Delay Time①	TPHL	Vcc=5V, IF=15mA	-	-	30	μs
	Rise Time①	tr	R _L =1.2kΩ	-	0.07	-	μs
	Fall Time①	tf		-	0.03	-	. µs

Connect a capacitor of more than 0.01 μ F between Vcc and GND.

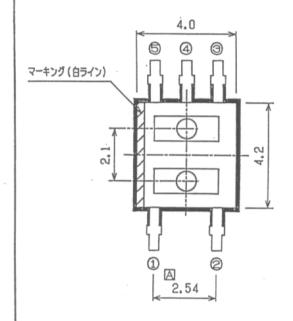
①Response Time Measuring Cuicuit

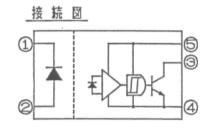




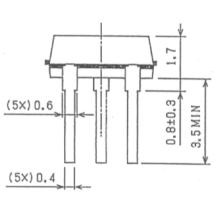


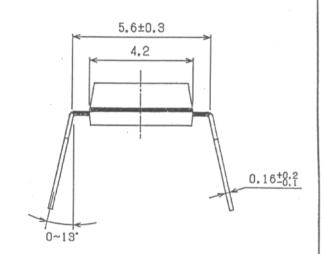
3.外形寸法図(単位:mm)





- ① CATHODE
- @ ANODE
- @ Vo
- 4 GND
- 5 Vcc





注記

- ・指示なき寸法公差: ±0.2
- | 一部はリード根元部にて規定する
- 色塗り部はバリを示す